P	CN Nu	mber:	2022	21021	001.2				P	CN Da	ate:	October 2022	r 21,
T	itle:	Qualifica	ation	of HF7	TF as ar	alterna	te A	ssembly and Test	site	for se	elect d	evices	
C	uston	ner Conta	ct:	PCN N	lanager	Dept	t:	Quality Servi	ces				
P	ropos	ed 1 st Shi	p Dat	e:	Apr 21	Apr 21, 2023 Sample requests accepted until: Nov 21, 2				21, 2022*	k		
*	Sample	e requests	recei	ived a	fter (No	v 21, 20	022)	will not be suppor	ted.				
Change Type:													
\geq	Ass	sembly Site	e			Desig	gn			Wafer Bump Site			
	Ass	sembly Pro	cess			Data	She	et		Wafe	r Bump	Materia	l
\triangleright	Ass	sembly Ma	terials	6		Part	num	per change				Process	
		chanical S	pecifi	cation	1	⊠ Test	Site			Wafe	r Fab S	Site	
\geq	Pac	king/Ship	ping/L	abelin	g	Test	Test Process			Wafe	r Fab I	Materials	
										Wafe	r Fab F	Process	
						PC	ON D	etails					
D	escrip	tion of Cl	hange	e:									
								e qualification of ferences are as fo			n addi	tional Ass	sembly
				ASESH			TIEMA			HFT	F		
		Mount Cor	npoun	nd	SID#EY1000063			4213245	3245		SID# A-18		
	Mold Compound		SID#	EN20005	515	8096859			SID#R	-30			
	Lead finish (Ro				(Rougl	iPdAuAg hened si ide top)	ngle	Matte Sn		(Ro	NiPd <i>l</i> ughene side	ed dual	
Т	est co	verage, in	sertio	ns, co	onditions	s will ren	nain (consistent with cu	ırren	t test	ing.		
R	eason	for Chan	ge:										
S	upply (continuity											
A	nticip	ated impa	act o	n Forr	n, Fit, F	unction	n, Qı	ality or Reliabili	y (p	ositi	ve / n	egative)) :
N	one												
Ir	mpact	on Envir	onme	ental I	Ratings								
cl		If below						tal ratings following changes to the	_	•			I
		RoHS			RE	ACH		Green Statu	IS		IE	C 62474	
	⊠ No	Change		\boxtimes	No Char	nge				\boxtimes	No Cl	nange	
										•			<u> </u>
C	hange	es to prod	luct ic	dentif	ication	resultir		om this PCN:					
	Asse	mbly Site	A	sseml	oly Site (22L)	Origin	As	sembly Country Co (23L)	ode		Asse	mbly City	,]
	ASESH			ASH			CHN		Shanghai				

Sample product shipping label (not actual product label)

CU6

HFT

TIEMA

HFTF

MYS

CHN

Melaka

Hefei

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q: MSL 2 /260C/1 YEAR SEAL DT

MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM: LBL: 5A (L)TO:3750



(1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483SI2

(P) (2P) REV: (2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

INA282AQDGKRQ1	LM3478QMM/NOPB	LM3478QMMX/S7002552	INA225AQDGKRQ1
	LM3478QMMX/E700254		
LM3476QMM/NOPB	8	LM3481QMM/NOPB	
	LM3478QMMX/E700266		
LM3476QMMX/NOPB	3	LM3481QMMX/NOPB	
LM3478MMX/E7002426	LM3478QMMX/NOPB	PGA308AQDGSRQ1	

Qualification Data

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date: 2 June 2022

Qualification Results (AEC-Q100)

Data Displayed as: Number of lots / Total sample size / Total failed

Typ e	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: INA225AQDGKRQ 1	Qual Device: INA282AQDGKRQ 1	Qual Device: LM3476QMMX / NOPB (AU)	Qual Device: LM3476QMMX / NOPB (CU)
					TEST G	ROUP A – ACCELE	RATED ENVIRONMENT	STRESS TESTS		
PC	A 1	J-STD-020 JESD22- A113	3	-	Auto Preconditioning	Level 1 - 260C	-	3/597/0	3/597/0	3/597/0
PC	A 1	J-STD-020 JESD22- A113	3	-	Auto Preconditioning	Level 2 - 260C	3/597/0	-	-	-
HAST	A 2	JEDEC JESD22- A110	3	77	Biased HAST, 130C	96 Hours	-	-	-	-
AC	A 3	JEDEC JESD22- A102	3	77	Autoclave, 121C	96 Hours	3/231/0	3/231/0	3/231/0	3/231/0
TC	A 4	JEDEC JESD22- A104 & Appendix 3	3	77	Temperature Cycle, Grade 1, -65/150C	500 Cycles	3/231/0	3/231/0	3/231/0	3/231/0
TC- WB P	A 4	MIL-STD883 Method 2011	3	30	Auto Post TC Bond Pull	Wires	3/90/0	3/90/0	3/90/0	3/90/0
PTC	A 5	JEDEC JESD22- A105	3	45	Power Temperature Cycle	1000 Cycles	N/A	N/A	N/A	N/A
HTSL	A 6	JEDEC JESD22-	3	45	High Temperature	420 Hours	3/135/0	3/135/0	3/135/0	3/135/0

		A103			Storage Life, 170C					
					TEST (SPOUD P ACCELE	ERATED LIFETIME SIMU	II ATION TESTS		
	•			1	1231 0	THOUP B-ACCELE	ENATED LIFETIME SHALL	JEATION 1E313	1	
HTO L	B 1	JEDEC JESD22- A108	3	77	Life Test, Grade 1, 125C	1000 Hours	-	-	-	-
ELFR	B2	AEC Q100- 008	3	80 0	Early Failure Rate, 125C	48 Hours	-	-	-	-
EDR	В3	AEC Q100- 005	3	77	NVM Endurance, Data Retention, Operational Life	-	N/A	N/A	N/A	N/A
					TEST GROUP C -	- PACKAGE ASSEM	IBLY INTEGRITY TESTS			
WBS	C1	AEC Q100- 001	3	30	Wire Bond Shear (Cpk>1.67)	Bonds, 5 devices (minimum)	3/90/0	3/90/0	3/90/0	3/90/0
WBP	C2	MIL-STD883 Method 2011	3	30	Wire Bond Pull (Cpk>1.67)	Wires, 5 devices (minimum)	3/90/0	3/90/0	3/90/0	3/90/0
SD	С3	JEDEC JESD22-B102	3	15	Surface Mount Solderability (Pb)	>95% Lead Coverage, 155C Dry Bake	3/45/0	3/45/0	3/45/0	3/45/0
SD	С3	JEDEC JESD22-B102	3	15	Surface Mount Solderability (Pb- Free)	>95% Lead Coverage, 155C Dry Bake	3/45/0	3/45/0	3/45/0	3/45/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Auto Physical Dimensions	(Cpk>1.67)	3/30/0	3/30/0	3/30/0	3/30/0
SBS	C5	AEC Q100- 010 AEC Q003	3	50	Solder Ball Shear	5 balls from a min. of 10 devices (Cpk>1.67)	N/A	N/A	N/A	N/A
LI	C6	JEDEC JESD22-B105	3	50	Lead Integrity	10 leads from a min. of 5 devices	N/A	N/A	N/A	N/A
					TEST GROUP D -	- DIE FABRICATIOI	N RELIABILITY TESTS			
EM	D1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
НСІ	D3	JESD60 & 28	1	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements

					TEST GROUP I	– ELECTRICAL VE	RIFICATION TESTS			
TEST	E1	Test program to supplier data sheet	All	All	Pre- and Post- Stress Function/Paramet er	-	N/A	N/A	N/A	N/A
НВМ	E2	AEC Q100- 002	3	3	Electrostatic Discharge, Human Body Model	0 Fails 2KV HBM (Classification 2 or better)	3/9/0	3/9/0	3/9/0	3/9/0
CDM	E3	AEC Q100- 011	3	3	Electrostatic Discharge, Charged Device Model	0 Fails 750V corner pins, 500V all other pins (Classification C4B or better)	3/9/0	3/9/0	3/9/0	3/9/0
LU	E4	AEC Q100- 004	3	6	Latch-Up	0 Fails	-	-	-	-
ED	E5	AEC Q100- 009 AEC Q003	3	30	Electrical Distributions	Cpk>1.67 at room, hot, cold test temperatures	-	-	-	-
FG	E6	AEC Q100- 007	-	-	Fault Grading	AEC Q100-007 unless otherwise specified	N/A	N/A	N/A	N/A
CHAR	E7	AEC Q003	-	-	Characterization	-	N/A	N/A	N/A	N/A
				•		OTHER QUALIFI	CATION TESTS			
MQ	-	Per Auto Requiremen ts	3	1	Manufacturability (Auto Assembly)	-	3/PASS	3/PASS	3/PASS	3/PASS
DSS	-	MIL-STD-883 Method 2019	3	10	Die Shear	Die	3/30/0	3/30/0	3/30/0	3/30/0
BPCC	-	-	3	5	Bond Pad Cratering Check	Bond Pads	3/15/0	3/15/0	3/15/0	3/15/0
LFA	-	-	3	15	Lead Finish Adhesion	Leads, 5 parts minimum	3/45/0	3/45/0	3/45/0	3/45/0
LP	-	1	3	24	Lead Pull	Leads, 8 parts minimum	3/72/0	3/72/0	3/72/0	3/72/0
XR	-	-	3	5	X-Ray	Top side only	3/15/0	3/15/0	3/15/0	3/15/0
YLD	-	Per datasheet specification s	3	All	FTY and Bin Summary	-	3/PASS	3/PASS	3/PASS	3/PASS
MSL	-	-	3	12	Moisture Sensitivity	Level 1 – 260C	-	3/36/0	3/36/0	3/36/0
MSL	-	-	3	12	Moisture Sensitivity	Level 2 – 260C	3/36/0	-	-	-

Qualification Results (AEC-Q100)
Data Displayed as: Number of lots / Total sample size / Total failed

Type I# Llest Spec I I Llest Name / Condition I Duration I	Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: TPD2S703QDGSRQ1
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			•	TEST GF STRESS	ROUP A – ACCELERATED ENVIRONMENT TESTS	_	
PC	A1	JEDEC J-STD-020 JESD22- A113	3	-	(Q006) Auto Preconditioning	Level 2 - 260C	3/1059/0
HAST	A2	JEDEC JESD22-A110	3	77	(Q006) Biased HAST	130C (96, 192* Hours)	3/231/0
AC .	A3	JEDEC JESD22-A102	3	77	(Q006) Auto Autoclave	121C, 2 atm (96 Hours)	3/231/0
ГС	A4	JEDEC JESD22-A104 and Appendix 3	3	77	(Q006) Auto T/C Grade 1	-65C/+150C (500, 1000* Cycles)	3/231/0
TC- WBP	A4	MIL-STD883 Method 2011	3	30	Auto Post TC Bond Pull	30 ball bonds, min. 5 units	3/90/0
PTC	A5	JEDEC JESD22-A105	3	45	Power Temperature Cycle	1000 Cycles	N/A
HTSL	A6	JEDEC JESD22-A103	3	45	(Q006) Auto High Temp. Storage Life Grade 1	175C (500, 1000* Hours)	3/135/0
				TEST G	ROUP B – ACCELERATED LIFETIME SIMUL	ATION TESTS	
HTOL	B1	JEDEC JESD22-A108	3	77	Auto High Temp Operating Life Grade 1	125C (1000, 2000* Hours); VCC max	3/231/0
ELFR	B2	AEC Q100-008	3	80 0	Early Failure Rate, 125C	48 Hours	-
EDR	В3	AEC Q100-005	3	77	NVM Endurance, Data Retention, Operational Life	-	N/A
				TEST	GROUP C – PACKAGE ASSEMBLY INTEG	RITY TESTS	
WBS	C1	AEC Q100-001	3	30	Wire Bond Shear (Cpk>1.67)	Bonds, 5 devices (minimum)	3/90/0
WBP	C2	MIL-STD883 Method 2011	3	30	Wire Bond Pull (Cpk>1.67)	Wires, 5 devices (minimum)	3/90/0
SD	С3	JEDEC JESD22-B102	3	15	Surface Mount Solderability (Pb)	>95% Lead Coverage, 155C Dry Bake	3/45/0
SD	C3	JEDEC JESD22-B102	3	15	Surface Mount Solderability (Pb- Free)	>95% Lead Coverage, 155C Dry Bake	3/45/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Auto Physical Dimensions	Cpk>1.67	3/30/0
SBS	C5	AEC Q100-010 AEC Q003	3	50	Solder Ball Shear	5 balls, 10 devices (min.), (Cpk>1.67)	N/A
LI	C6	JEDEC JESD22-B105	3	50	Lead Integrity	10 leads from a min. of 5 devices	N/A
	•		•	TES	ST GROUP D – DIE FABRICATION RELIABII	LITY TESTS	
EM	D 1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements
TDDB	D 2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	Completed Per Process Technology Requirements
НСІ	D 3	JESD60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements

NBTI	D 4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology
							Requirements
SM	D 5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements
	•			Т	EST GROUP E – ELECTRICAL VERIFICATION	N TESTS	
TEST	E1	Test program to supplier data sheet	All	All	Pre- and Post-Stress Function/Parameter	-	N/A
НВМ	E2	AEC Q100-002	3	3	Electrostatic Discharge, Human Body Model	0 Fails 2KV HBM (Classification 2 or better)	3/9/0
CDM	E3	AEC Q100-011	3	3	Electrostatic Discharge, Charged Device Model	0 Fails 750V corner pins, 500V all other pins (Classification C4B or better)	3/9/0
LU	E4	AEC Q100-004	3	6	Latch-Up	0 Fails	-
ED	E5	AEC Q100-009 AEC Q003	3	30	Electrical Distributions	Cpk>1.67 at room, hot, cold test temperatures	3/90/0
FG	E6	AEC Q100-007	-	-	Fault Grading	AEC Q100-007 unless otherwise specified	N/A
CHAR	E7	AEC Q003	-	-	Characterization	-	N/A
OTHER (QUALIF	ICATION TESTS	ı				1
MQ	-	-	-	-	Manufacturability (Auto Assembly)	(per automotive requirements)	3/PASS
DS	-	MIL-STD-883 Method 2019	1	5	Die Shear	QSS 009-009	3/30/0
ВРСС		-	3	5	Bond Pad Cratering Check	Bond Pads	3/15/0
XR	-	-	3	5	X-Ray	Top side only	3/15/0
YLD	-	Per datasheet specifications	3	All	FTY and Bin Summary	-	3/PASS
MSL	-	-	3	12	Moisture Sensitivity (Cu Wire)	Level 2 - 260C	3/36/0
SA			3	22	Salt Atmosphere	24 Hours	3/66/0
VM			-	-	Visual / Mechanical	(per manufacturing site specification)	3/30/0
AEC-Q0	06 QUA	LIFICATION TESTS					
-	-	-	-	-	(Q006) Cross Section, Post Stress	BHAST 130C, 192 Hours	3/3/0
-	-	-	-	-	(Q006) Wire Bond Shear, Post Stress	BHAST 130C, 192 Hours	3/90/0
-	-	-	-	-	(Q006) Bond Pull Over Ball Bond, Post Stress	BHAST 130C, 192 Hours	3/90/0
-	-	-	-	-	(Q006) Bond Pull Over Stitch Bond, Post Stress	BHAST 130C, 192 Hours	3/90/0
-	-	-	-	-	(Q006) SAM Analysis, Post Stress	BHAST 130C, 192 Hours	3/66/0
-	-	-	-	-	(Q006) Cross Section, Post Stress	T/C Grade 1, 1000 Cycles	3/3/0
-	-	-	-	-	(Q006) Wire Bond Shear, Post Stress	T/C Grade 1, 1000 Cycles	3/90/0
-	-	-	-	-	(Q006) Bond Pull Over Ball Bond, Post Stress	T/C Grade 1, 1000 Cycles	3/90/0

-	-	-	-	-	(Q006) Bond Pull Over Stitch Bond, Post Stress	T/C Grade 1, 1000 Cycles	3/90/0
-	-	-	-	-	(Q006) SAM Analysis, Post Stress	T/C Grade 1, 1000 Cycles	3/66/0
-	-	-	-	-	(Q006) Cross Section, Post Stress	HTSL Grade 1, 1000 Hours	3/3/0
Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: TPD2S703QDGSRQ 1
-	-	-	-	-	Bond Pull, over ball	5 devices (min.), 30 wires, Cpk>1.67	3/90/0
-	-	-	-	-	Bond Pull, over stitch	5 devices (min.), 30 wires, Cpk>1.67	3/90/0

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD, LU

Room: AC/uHAST

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail					
WW Change Management Team	PCN www admin_team@list.ti.com					

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